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LOW-POWER DUAL 2-INPUT POSITIVE-AND GATE

Check for Samples: SN74AUP2G08

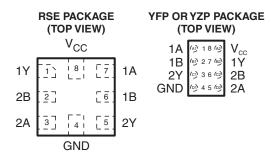
FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Max)
- Low Dynamic-Power Consumption (C_{pd} = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Schmitt-Trigger Action Allows Slow Input Transition and Better Switching Noise Immunity at the Input

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(V<sub>hys</sub> = 250 mV Typ at 3.3 V)
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DCU PACKAGE DQE PACKAGE (TOP VIEW) (TOP VIEW) V_{cc} □ V_{CC} 1A <u>_8</u>_ 1A 🗆 1 8 1B ī Z 1Y 21 🔟 1Y 1B 🖂 2 7 <u>_6</u> 3 2B 2Y 2Y 🖂 3 6 🗔 2B GND 2A GND 🗌 4 5 □ 2A

- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 5.9 ns Max at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

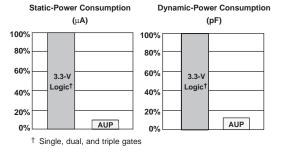


Figure 1. AUP - The Lowest-Power Family

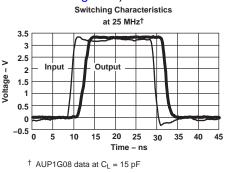


Figure 2. Excellent Signal Integrity

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SN74AUP2G08

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This dual 2-input positive-AND gate performs the Boolean function $Y = A \bullet B$ or $Y = \overline{A + B}$ in positive logic.

NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

	UNDER			
T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74AUP2G08YFPR	HE_
–40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP2G08YZPR	HE_
	X2SON – DQE	Reel of 5000	SN74AUP2G08DQER	PR
	QFN – RSE	Reel of 5000	SN74AUP2G08RSER	PR
	VSSOP – DCU	Reel of 3000	SN74AUP2G08DCUR	H08_

ORDERING INFORMATION⁽¹⁾

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

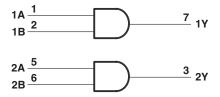
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free). DCU: The actual top-side marking has one additional character to denote wafer fab/assembly site.

INP	UTS	OUTPUT						
Α	В	Y						
L	L	L						
L	Н	L						
Н	L	L						
Н	Н	Н						

FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for DCU, YFP, and YZP packages.



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state ⁽²⁾	-0.5	4.6	V
Vo	Output voltage range in the high or low stat	te ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{ОК}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
		DCU package		227	
		DQE package		261	
θ_{JA}	Package thermal impedance ⁽³⁾	RSE package		253	°C/W
		YFP package		98.8	
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

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ISTRUMENTS

EXAS

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT									
V _{CC}	Supply voltage		0.8	3.6	V									
		$V_{CC} = 0.8 V$	V _{CC}											
M		V_{CC} = 1.1 V to 1.95 V	$0.65 \times V_{CC}$		V									
V _{IH}	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.6		v									
		V_{CC} = 3 V to 3.6 V	2											
		$V_{CC} = 0.8 V$		0										
V	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$			0.35 × V _{CC}	V									
V _{IL}	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V									
		V_{CC} = 3 V to 3.6 V		0.9										
VI	Input voltage		0	3.6	V									
Vo	Output voltage		0	V_{CC}	V									
	High lovel output ourgest	$V_{CC} = 0.8 V$		-20	μA									
		V _{CC} = 1.1 V		-1.1										
		High lovel output ourrent	High lovel output ourrent	Lish lovel output ourrest	LPak land a david anne at	I Pak Jawahan dan diananan di	1 Pate lasse based as more of	Lieb level even a summer		Lich lough output ourrest	High lovel output current	$V_{CC} = 1.4 V$		-1.7
I _{OH}	High-level output current	$V_{CC} = 1.65$		-1.9	mA									
	V _{CC} = 2.3 V			-3.1										
		$V_{CC} = 3 V$		-4										
		V _{CC} = 0.8 V		20	μA									
		V _{CC} = 1.1 V		1.1										
		$V_{CC} = 1.4 V$		1.7										
I _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA									
		V _{CC} = 2.3 V		3.1										
		$V_{CC} = 3 V$		4										
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$		200	ns/V									
T _A	Operating free-air temperature		-40	85	°C									

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS	N	TA	= 25°C	$T_A = -40^{\circ}$	C to 85°C		
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MAX	MIN	MAX	UNIT	
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} – 0.1		V _{CC} - 0.1			
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		0.7 × V _{CC}			
	I _{OH} = -1.7 mA	1.4 V	1.11		1.03			
	I _{OH} = -1.9 mA	1.65 V	1.32		1.3			
V _{OH}	$I_{OH} = -2.3 \text{ mA}$		2.05		1.97		V	
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85			
	I _{OH} = -2.7 mA	2.1/	2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1		0.1		
	I _{OL} = 1.1 mA 1.1 \			0.3 × V _{C0}	;	$0.3 \times V_{CC}$		
	I _{OL} = 1.7 mA	1.4 V		0.3		0.37		
	I _{OL} = 1.9 mA	1.65 V		0.3		0.35	V	
V _{OL}	I _{OL} = 2.3 mA	0.0.1/		0.3		0.33	v	
	I _{OL} = 3.1 mA	2.3 V		0.44	L I	0.45		
	I _{OL} = 2.7 mA	0.14		0.3		0.33		
	$I_{OL} = 4 \text{ mA}$	3 V		0.44	ŧ.	0.45		
II A or B input	$V_I = GND$ to 3.6 V	0 V to 3.6 V		0.1		0.5	μA	
off	V_{I} or $V_{O} = 0$ V to 3.6 V	0 V		0.2	2	0.6	μA	
ΔI _{off}	V_{I} or V_{O} = 0 V to 3.6 V	0 V to 0.2 V		0.2	2	0.9	μΑ	
lcc	$V_1 = GND \text{ or } I_0 = 0$ (V_{CC} to 3.6 V)	0.8 V to 3.6 V		0.5	5	0.9	μA	
ΔI _{CC}	$V_{I} = V_{CC} - 0.6 V^{(1)}, I_{O} = 0$	3.3 V		40)	50	μΑ	
<u>^</u>		0 V		2			- 5	
C _i	$V_{I} = V_{CC}$ or GND	3.6 V		2			pF	
C _o	$V_{O} = GND$	0 V		3			pF	

(1) One input at V_{CC} – 0.6 V, other input at V_{CC} or GND

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	_ = 25°C	;	T _A = −40°C t	o 85°C	UNIT
PARAIVIETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		19.8				
			1.2 V ± 0.1 V	0.5	7.8	18.8	0.5	19.8	
	A or B	Y	1.5 V ± 0.1 V	0.5	5.4	11.8	0.5	13.9	
t _{pd}	AUD	ř	1.8 V ± 0.15 V	0.5	4.3	9	0.5	11.1	ns
			2.5 V ± 0.2 V	0.5	3	5.7	0.5	7.8	
			3.3 V ± 0.3 V	0.5	2.4	4.6	0.5	5.9	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	Т,	₄ = 25°C		T _A = −40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		23.1				
			1.2 V ± 0.1 V	0.5	8.9	21.1	0.5	22	
	A or D	v	1.5 V ± 0.1 V	0.8	6.3	13.2	0.5	15.1	~~
t _{pd}	A or B	ř	1.8 V ± 0.15 V	0.6	5	10.1	0.5	12.2	ns
			2.5 V ± 0.2 V	0.5	3.6	7.4	0.5	9	
			3.3 V ± 0.3 V	0.5	2.9	5.1	0.5	6.5	

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	_λ = 25°C		T _A = −40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		24.7				
			1.2 V ± 0.1 V	0.5	9.8	21.7	0.5	22.7	
	A or D	v	1.5 V ± 0.1 V	1.3	4.6	14	0.5	15.7	~~~
t _{pd}	A or B	ř	1.8 V ± 0.15 V	1.2	5.5	10.6	0.5	12.6	ns
			$2.5 \text{ V} \pm 0.2 \text{ V}$	0.7	4	7	0.5	8.9	
			3.3 V ± 0.3 V	0.9	3.3	5.5	0.5	6.9	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	т,	₄ = 25°C		$T_A = -40^{\circ}C tc$	85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		31.8				
			1.2 V ± 0.1 V	0.6	12.6	26.3	0.5	27	
	A	v	1.5 V ± 0.1 V	2.5	9	16.6	0.7	18.3	
t _{pd}	A or B	ř	1.8 V ± 0.15 V	2.3	7.3	12.9	0.5	14.8	ns
			2.5 V ± 0.2 V	2.1	5.4	8.8	0.8	10.5	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	2.1	4.5	6.7	0.9	8.2	

OPERATING CHARACTERISTICS

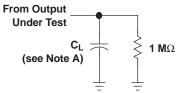
 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
			1.2 V ± 0.1 V	4	pF
6	Dower dissinction conscitutes	f = 10 MHz	1.5 V ± 0.1 V	4	
C _{pd}	Power dissipation capacitance		1.8 V ± 0.15 V	4	
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

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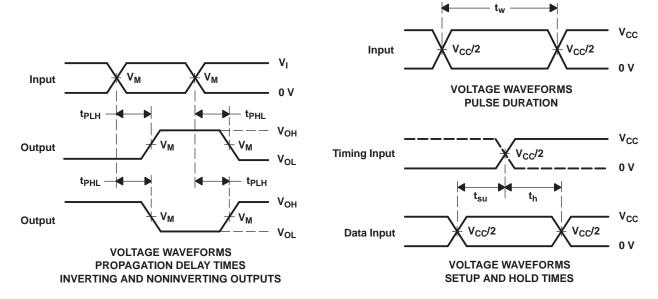
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PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Duration)



	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}

LOAD CIRCUIT



NOTES: A. CL includes probe and jig capacitance.

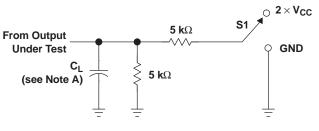
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



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PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)

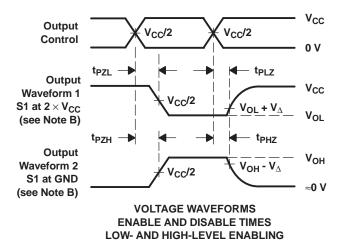


TEST	S 1
t _{PLZ} /t _{PZL} t _{PHZ} /t _{PZH}	$2 \times V_{CC}$ GND

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LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	$\begin{array}{c} V_{CC} \texttt{=} \texttt{3.3 V} \\ \pm \texttt{0.3 V} \end{array}$
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V_{Δ}	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	-		Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74AUP2G08DCUR	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H08R	Samples
SN74AUP2G08DQER	ACTIVE	X2SON	DQE	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	PR	Samples
SN74AUP2G08RSER	ACTIVE	UQFN	RSE	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	PR	Samples
SN74AUP2G08YFPR	ACTIVE	DSBGA	YFP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	HEN	Samples
SN74AUP2G08YZPR	ACTIVE	DSBGA	YZP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	HEN	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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10-Dec-2020

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G08DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP2G08DQER	X2SON	DQE	8	5000	180.0	8.4	1.2	1.6	0.55	4.0	8.0	Q1
SN74AUP2G08RSER	UQFN	RSE	8	5000	180.0	8.4	1.7	1.7	0.7	4.0	8.0	Q2
SN74AUP2G08YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1
SN74AUP2G08YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

18-Jan-2020



*All dimensions are nominal

Device Package Type		Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
SN74AUP2G08DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0	
SN74AUP2G08DQER	X2SON	DQE	8	5000	202.0	201.0	28.0	
SN74AUP2G08RSER	UQFN	RSE	8	5000	202.0	201.0	28.0	
SN74AUP2G08YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0	
SN74AUP2G08YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0	

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



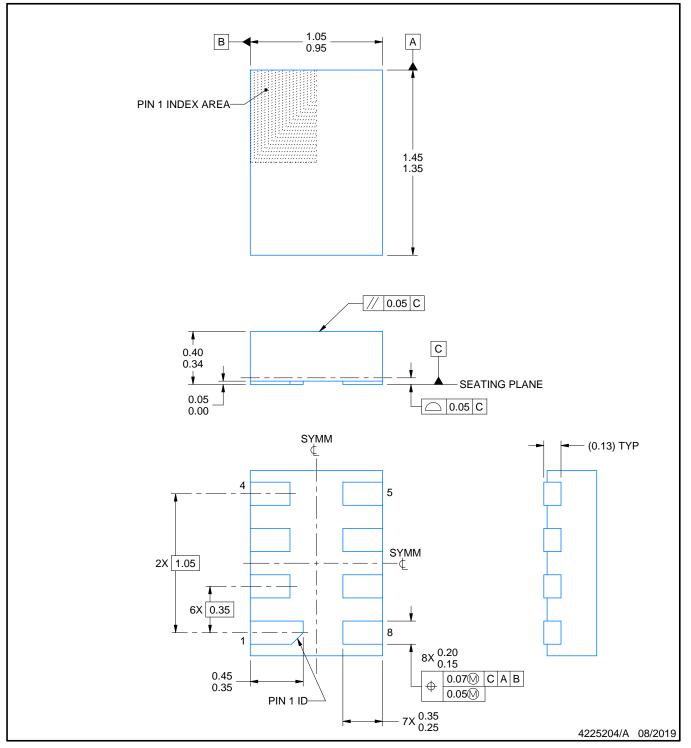
DQE0008A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This package complies to JEDEC MO-287 variation X2EAF.

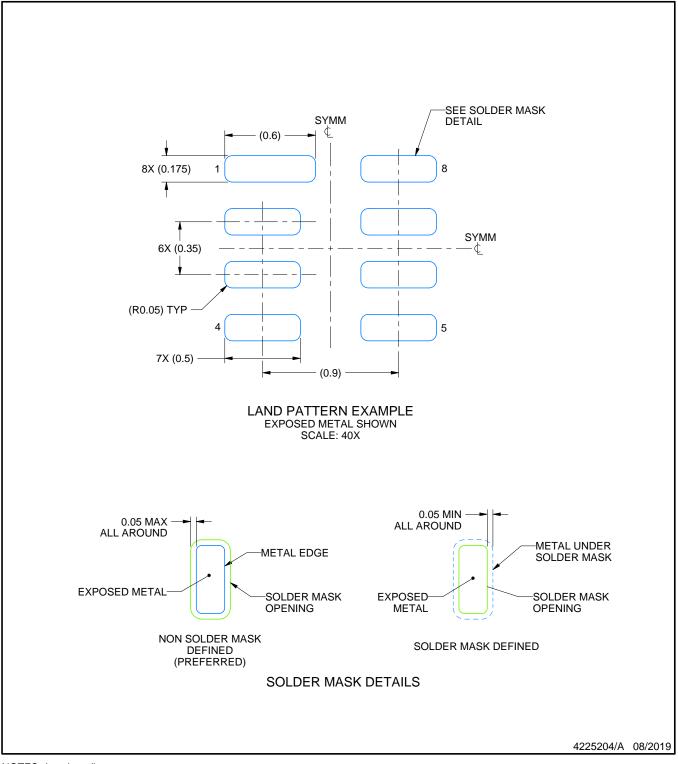


DQE0008A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

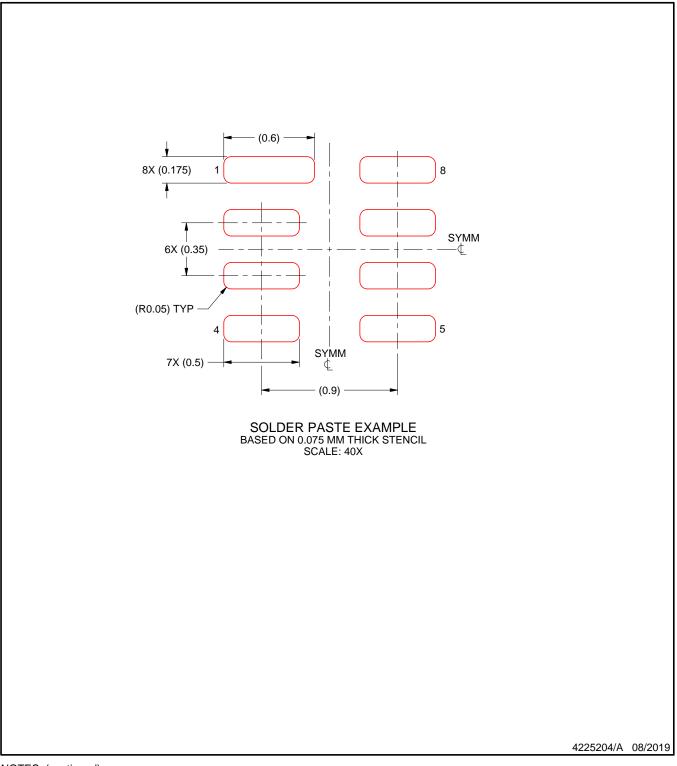


DQE0008A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



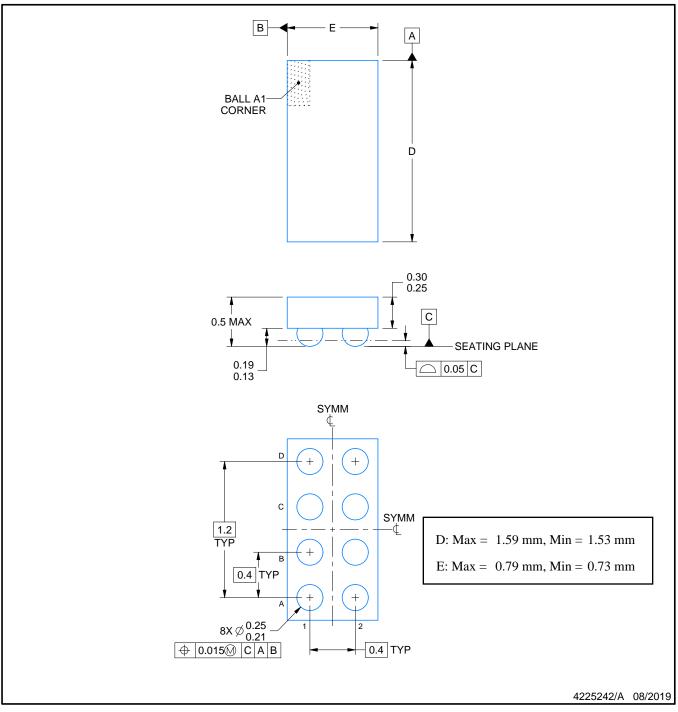
YFP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

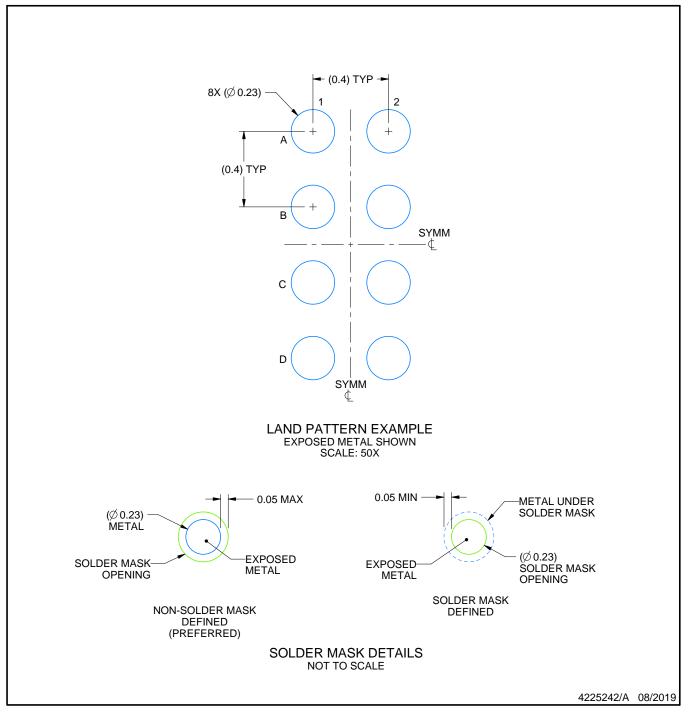


YFP0008

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

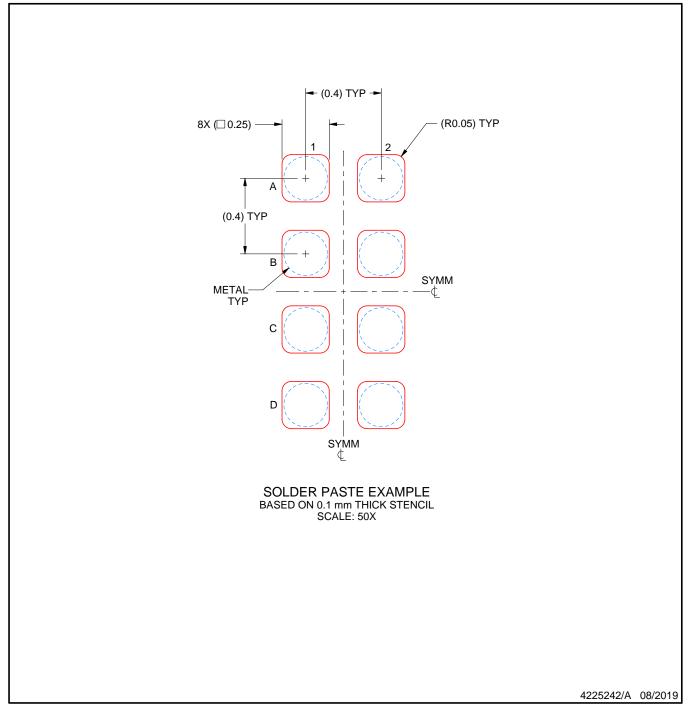


YFP0008

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



RSE0008A



PACKAGE OUTLINE

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

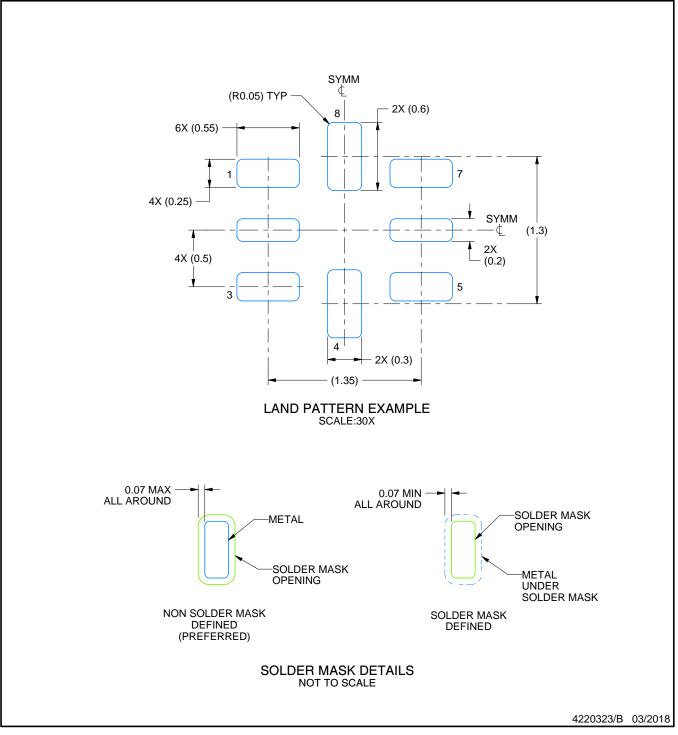


RSE0008A

EXAMPLE BOARD LAYOUT

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

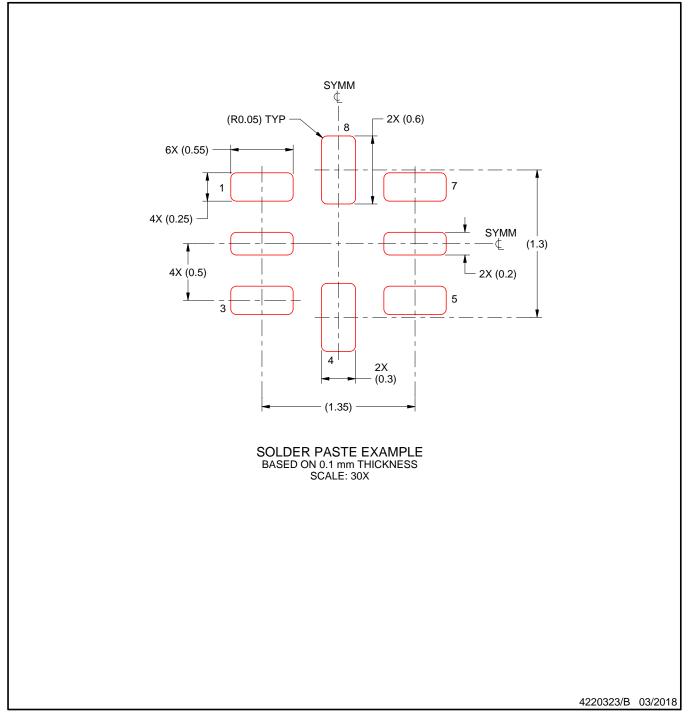


RSE0008A

EXAMPLE STENCIL DESIGN

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



YZP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



YZP0008

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



YZP0008

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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